



An Improved Active-Clamped DC-DC Converter with Modified PI Controller

B.Gamya¹, Ramesh R.Halakurki²

PG scholar [PE], Department of EEE, SITAMS, Chittoor, Andhra Pradesh, India¹

Professor, Department of EEE, SITAMS, Chittoor, Andhra Pradesh, India²

ABSTRACT: A new dual active-clamping dc-dc converter is proposed to obtain high efficiency. The proposed converter employs a dual active-clamping technique, while a resonant voltage doubler rectifier scheme controls the output voltage with the pulse width modulation technique. The dual active-clamping circuit serves to recycle the energy stored in the leakage inductor or the magnetizing inductor and provides zero-current turn-off switching. The voltage stresses of the main switches are clamped. The voltage transient spikes across the dual active-clamping circuit and the current stress of the current-fed side switches are limited by auxiliary dual active-clamping circuits on both sides, and zero-current switching is achieved. Also, to reduce the output voltage variation, a modified PI controller is suggested.

KEYWORDS: Converter, active-clamping, voltage doubler rectifier, high-efficiency, zero current switching (ZCS).

I. INTRODUCTION

The global demand for electrical energy has continuously increased over the last few decades. Environment and energy have become serious concerns in today's world. Alternative sources of energy generation have drawn more and more attention in recent years. Photovoltaic (PV) sources are predicted to become the biggest contributors to electricity generation among all renewable energy generation candidates by 2040[1].The PV module need a high step-up dc-dc converter to interface the low dc voltage to the high dc voltage before making it to ac for grid-tie applications [2].A step-up dc-dc converter is needed with a high step-up ratio and high-efficiency. Among the investigated topologies, the active-clamped step-up dc-dc converters are gaining its popularity. The intention of this paper is to propose a high-efficiency dc-dc converter for the photovoltaic module integrated (PV-MIC) system [3] where a high step-up dc-dc converter and low power inverter are attached at the back of each panel.

For a power level around 250-W in the PV-MIC system applications, several high step-up dc-dc converters were proposed for the power conversion form low dc voltage to high dc voltage. The half-bridge dc-dc converter has been presented to reduce switching power losses at high-voltage side [4]. The output diodes are turned OFF at zero current by using the voltage doubler rectifier. However, an additional half-wave rectifier is needed, which increases switching power losses. Alternatively, the active-clamped dc-dc converter has been used for low-voltage PV sources [5]. It uses the active-clamping circuit and the resonant voltage doubler rectifier. However, the active-clamping circuit increases the voltage stress of power switches at low-voltage side, causing high switching power losses. Additionally, thermal management problems should be considered for a practical design of the PV MIC system. Although, the soft-switched half-bridge dc-dc converters and active-clamped dc-dc converters were proposed but they does not have a high step-up voltage conversion ratio, thus requiring a high turns ratio. High turns ratio is not favoured due to high leakage inductance at the secondary side, which causes high switching losses at the output diodes.

In this paper, an improved active-clamped dc-dc converter [6] is presented by dual active-clamping circuit. The proposed converter uses the dual-active clamping circuit and the voltage-doubler rectifier [7] in order to achieve a high step-up ratio and soft switching operation. The output diodes in the proposed converter can be turned off at zero-current, which can reduce the switching power losses at high output voltage applications. The leakage inductance of the transformer and the resonant capacitor of the voltage doubler rectifier are utilized for the series-resonant circuit to achieve zero current switching of the output diodes. Furthermore, the output voltage stress can be clamped as output voltage, which reduces the voltage rating of the output diodes. To reduce the output voltage variation, a modified PI

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controller is suggested. The performance of the proposed converter evaluated on a 200-W PV-MIC system. A high-efficiency of 97.5% is achieved to generate 350V high output voltage from 50-V low PV module voltage.

II. CONVERTER OPERATION

Figure.1 shows the circuit diagram of proposed dc-dc converter. The step-up dc-dc converter consists of a boost type of a dual active-clamping circuit (S_2, S_3, C_c), a transformer T, and the resonant voltage doubler rectifier ($L_{lk}, C_r, D_{o1}, D_{o2}$). Also, the converter consists of main switches (S_1, S_4) and auxiliary switches (S_2, S_3) operate complementarily with a short dead time. All switches are the MOSFET's. ($D_{s1} - D_{s4}$) Are the body diodes of switches ($S_1 - S_4$) and ($C_{s1} - C_{s4}$) are the output capacitors of switches ($S_1 - S_4$), respectively. The transformer T has the magnetizing inductor L_m and leakage inductor L_{lk} with the turn's ratio of 1: N, where $N = \frac{N_s}{N_p}$. C_i is the input capacitor. C_c is the clamping capacitor. C_o is the output capacitor. The capacitors C_i, C_c and C_o are large enough so that their voltages V_i, V_c and V_o are considered constant, respectively. L_{lk} is assumed to be much smaller than L_m . The capacitor C_r is the resonant capacitor. C_r Resonates with the leakage inductor L_{lk} . Thus, the resonant capacitor voltage V_r is not considered constant for one switching period.

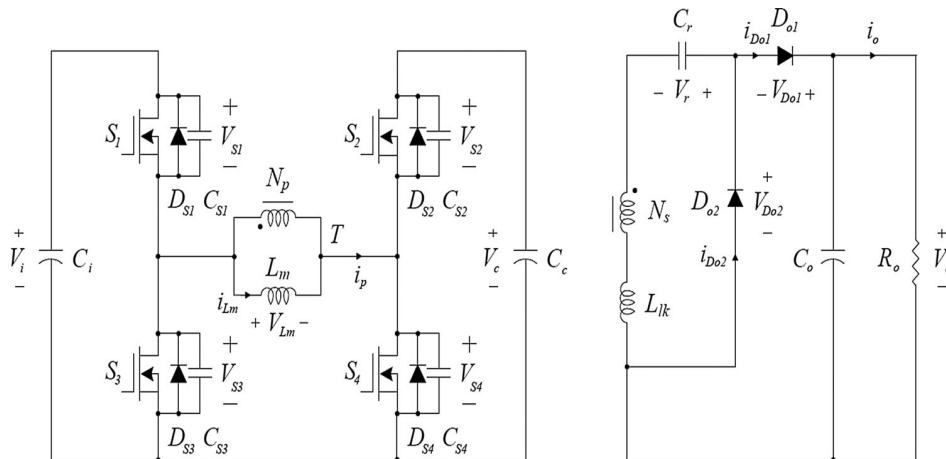


Figure.1 Circuit diagram of proposed dc-dc converter.

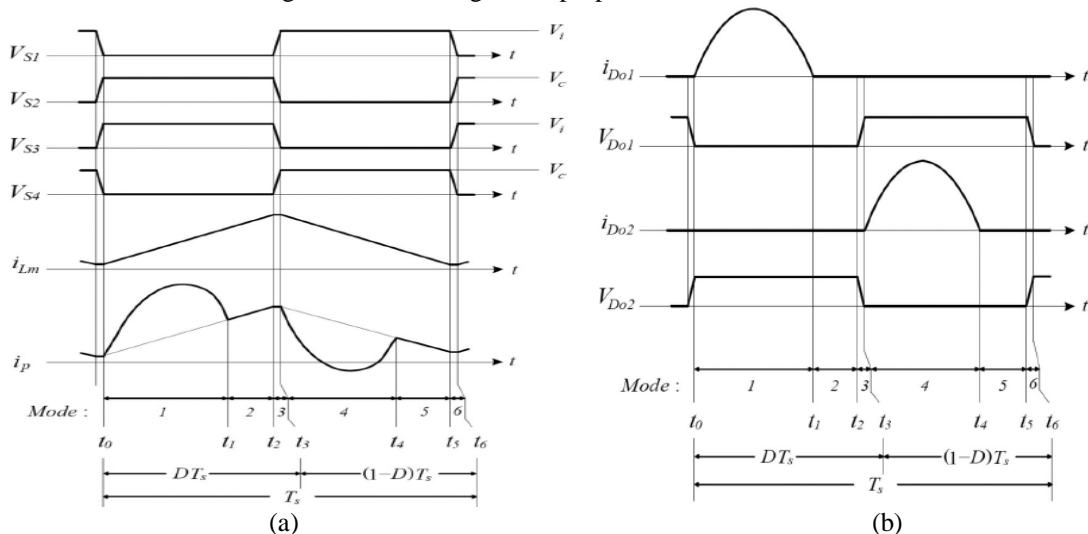


Figure.2 shows the switching waveforms of the proposed converter during one switching period T_s . Figure.2 (a) shows the switching waveforms at primary side. Figure.2 (b) shows the switching waveforms at secondary side.



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The proposed converter has six switching modes during T_s :

Mode 1 $[t_0, t_1]$: At $t = t_0$, S_1 and S_4 are turned ON. Since $V_{Lm} = V_i$, the magnetizing inductor current i_{Lm} increases linearly as

$$i_{Lm}(t) = i_{Lm}(t_0) + \frac{V_i}{L_m}(t - t_0) \quad (1)$$

At the secondary side, when NV_i is applied to the secondary winding of T. The output diode D_{o1} is turned ON. The series-resonant circuit consisting of L_{lk} and C_r is formed. Series resonance between L_{lk} and C_r , the energy stored in C_r is transferred to C_o . the angular resonant frequency ω_r is

$$\omega_r = 2\pi f_r = \frac{1}{\sqrt{L_{lk}C_r}} \quad (2)$$

Where f_r is the resonant frequency. By referring $i_{D_{o1}}$ to the primary side, the primary current i_p is expressed as

$$i_p(t) = i_p(t_0) + \frac{V_i}{L_m}(t - t_0) + Ni_{D_{o1}}(t) \quad (3)$$

The output diode current $i_{D_{o1}}$ is given by

$$i_{D_{o1}}(t) = \frac{V_o - NV_i - V_r}{Z_r} \sin \omega_r (t - t_0) \quad (4)$$

The resonant impedance Z_r is expressed as

$$Z_r = \sqrt{\frac{L_{lk}}{C_r}} \quad (5)$$

Mode 2 $[t_1, t_2]$: At $t = t_1$, the half-resonant period of the series resonance is finished. The output diode current $i_{D_{o1}}$ is zero before D_{o1} is turned OFF. ZCS of D_{o1} is achieved without any reverse recovery current.

Mode 3 $[t_2, t_3]$: At $t = t_2$, S_1 and S_4 are turned OFF. The primary current i_p charges C_{s1} and C_{s4} and discharges C_{s2} and C_{s3} . V_{s1} and V_{s4} increases from zero to V_i . V_{s2} and V_{s3} decreases from V_c to zero. Since the switch output capacitor C_s is very small, the time interval is considered as negligible comparing to T_s .

Mode 4 $[t_3, t_4]$: At $t = t_3$, S_2 and S_3 are turned ON. Since $V_{Lm} = -V_c$, the magnetizing inductor current i_{Lm} decreases linearly as

$$i_{Lm}(t) = i_{Lm}(t_3) - \frac{V_c}{L_m}(t - t_3) \quad (6)$$

When NV_c is reversely applied across the secondary winding of T. The output diode D_{o2} is turned ON. The series resonant circuit between L_{lk} and C_r is formed again. By referring the output diode current $i_{D_{o2}}$ to the primary side, i_p is expressed as

$$i_p(t) = i_p(t_3) - \frac{V_c}{L_m}(t - t_3) - Ni_{D_{o2}}(t) \quad (7)$$

Where the output diode current $i_{D_{o2}}$ is given by

$$i_{Lm}(t) = i_{Lm}(t_3) - \frac{NV_c + V_r}{Z_r} \sin \omega_r (t - t_3) \quad (8)$$

Mode 5 $[t_4, t_5]$: At $t = t_4$, the half-resonant period of the series resonance is finished. The $i_{D_{o2}}$ is zero before D_{o2} is turned OFF without any reverse recovery current.

Mode 6 $[t_5, t_6]$: At $t = t_5$, S_2 and S_3 are turned OFF. The primary current i_p charges C_{s2} and C_{s3} and discharges C_{s1} and C_{s4} . V_{s2} and V_{s3} increase from zero to V_c . V_{s1} and V_{s4} decrease from V_i to zero. Since the capacitor C_s is very small, time interval is negligible as compared to T_s .

By the voltage-second balance relation on the magnetizing inductor L_m , the voltages V_c and V_r are expressed as

$$V_c = \frac{D}{1-D} V_i \quad (9)$$

$$V_r = (1 - D)V_o \quad (10)$$

For the voltage-second balance relation on the secondary winding of T during T_s , the following relation between the output voltage V_o and the input voltage V_i is obtained as

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$$\frac{V_o}{V_i} = \frac{N}{1-D} \quad (11)$$

The maximum voltage stress of S_1 and S_3 is confined to the input voltage V_i . The voltage stress of S_2 and S_4 is confined to the clamping capacitor voltage V_c . Figure.3 shows the relation between the clamping capacitor voltage V_c and the duty ratio D . The dual active-clamping is used in the proposed converter. The clamping capacitor voltage in case of the dual active-clamping circuit is always lower than the clamping capacitor voltage in case of the conventional active-clamping circuit. It means that the switch voltage stress of the proposed converter is always lower than the switch voltage stress of previous converter [5] using the conventional active-clamping circuit. Especially, when the duty ratio is below 0.5, the clamping capacitor voltage can be lower than the input voltage V_i . It is critically beneficial in low-voltage PV applications where more than 50% of power losses are lost as switching power losses.

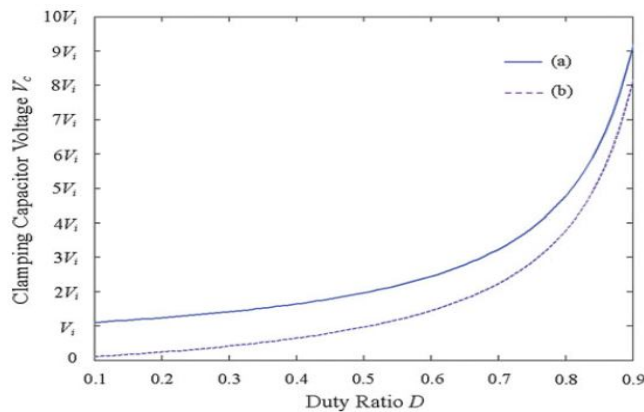


Figure.3.Relation between the clamping capacitor voltage V_c and the duty ratio D : (a) in case conventional active clamping circuit and (b) in case of the dual active clamping circuit.

III. CONTROL STRATEGY

A. A modified PI controller is to reduce output voltage variation:

The output voltage V_o is controlled with duty ratio D . Then, the duty ratio D is represented by

$$D = D_n + D_c \quad (12)$$

Where D_n is a nominal duty ratio and D_c is a controlled duty ratio. The nominal duty ratio D_n and the controlled duty ratio D_c can be respectively, represented as

$$D_n = 1 - \frac{NV_i}{V_o} \quad (13)$$

$$D_c = \frac{NL_m \Delta i_{Lm}}{V_o T_s} \quad (14)$$

Then, the duty ratio D becomes

$$D = D_n + D_c = 1 - \frac{NV_i}{V_o} + \frac{NL_m \Delta i_{Lm}}{V_o T_s} \quad (15)$$

To regulate the output voltage for the output load variation, the conventional PI controller can be used for the controlled duty ratio D_c as

$$D_c = K_p e + K_i \int e dt \quad (16)$$

$$e = V_o^* - V_o \quad (17)$$

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Where V_o^* is the reference output voltage, e is the voltage error between V_o^* and V_o , and K_p and K_i are the PI control gains of the controller, respectively. The regulated output voltage is an important factor achieving high performance. The PV MIC system should provide a fast dynamic response for grid power demand in case of the distributed generation using the renewable energy sources. Where the local load power increases or decreases abruptly, the output voltage of the dc-dc converter fluctuates as the inverter load changes. It might cause grid current harmonic distortion, damaging the grid-connected power generation systems. However, because the conventional PI controller controls the output slowly, the output voltage variation exists. To reduce the output voltage variation, a modified PI controller is suggested.

The suggested controller is

$$D_c = K_p e_m + K_i \int e_m dt \quad (18)$$

$$e_m = (V_o^* - V_o) \times \left(1 + \frac{|V_o^* - V_o|}{\alpha}\right) \quad (19)$$

Where e_m is the modified error between V_o^* and V_o . α is the scaling factor. The error term $\frac{|V_o^* - V_o|}{\alpha}$ is included as comparing to the conventional PI controller. Figure 4 shows the difference between the error terms of the conventional PI controller, the error term of the suggested PI controller in case of $\alpha = 15$, and the error term of the suggested PI controller in case of $\alpha = 20$. The horizontal axis shows the difference between V_o^* and V_o . The vertical axis shows e_m and e . Due to the term $\frac{|V_o^* - V_o|}{\alpha}$, a large error between V_o^* and V_o increases e_m more than e . Thus, if the voltage error is large, the output voltage can be rapidly controlled as the suggested controller has large gain. In contrast, if the voltage error is small, the suggested controller gives almost the same characteristic as the conventional PI controller.

B. Digital implementation:

Fig. 5 shows the control block diagram of the output voltage controller. The voltage error e is calculated by comparing the reference output voltage V_o^* to the measured output voltage V_o . The modified error e_m is generated through the modified error calculation. Then, the PI controller is used to generate the duty ratio to control the power switches. The controlled duty ratio D_c of the voltage controller only generates the output voltage drop required to regulate the output voltage. With the addition of the nominal duty ratio D_n to the converter, the relation between D_c and Δi_{Lm} of the converter becomes a first-order linear dynamic system with easy controllability. Thus, the addition of the nominal duty ratio D_n relaxes the burden of the voltage controller, improving the dynamic performance.

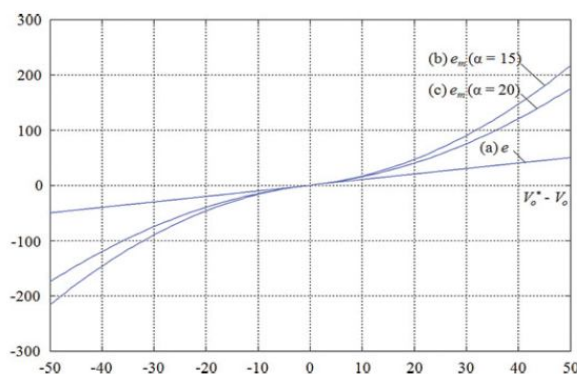


Figure.4

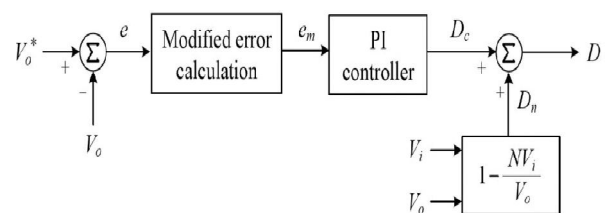


Figure.5

Figure.4. difference between the clamping capacitor V_c and the duty ratio D : (a) in case of the conventional active-clamping circuit and (b) in case of dual active-clamping circuit .Figure.5. Control block diagram of the output voltage controller.

IV. EXPERIMENTAL RESULTS

Figure.6. shows the primary current i_p and switch voltages V_{s1} and V_{s3} for 200-W output power at 50-V input voltage. As shown in figure.6. V_{s1} and V_{s3} are clamped at the input voltage respectively. Figure.7 shows the primary current i_p , clamping capacitor voltage V_C , and switch voltages V_{s2} and V_{s4} for 200-W output power at 50-V input voltage. The clamping capacitor voltage V_C is 48V. V_{s2} and V_{s4} are clamped at 48V. Which is even lower than the input voltage V_i . The voltage stress of power switches is significantly reduced. Figure.8. shows the output diode voltages V_{D01} and V_{D02} and output diode currents i_{D01} and i_{D02} for output load.

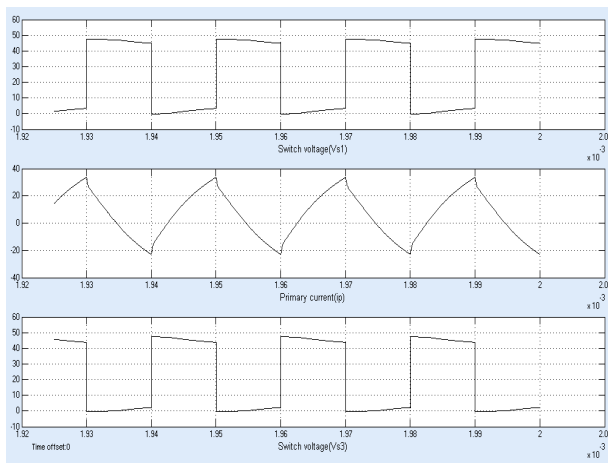


Figure.6

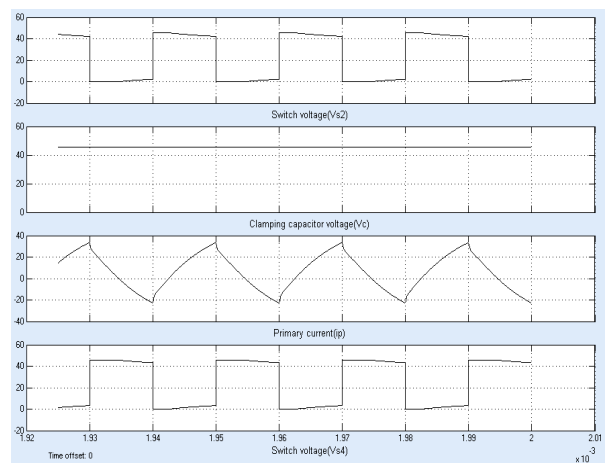


Figure.7

Figure.6. Experimental results: primary current i_p : 10A/ division; switch voltage V_{s1} : 10V/division Switch voltage V_{s3} : 10V/division, 10 μ s/division. Figure.7. Experimental results: primary current i_p : 10A/ division; clamping capacitor voltage V_C ; 50 V /division; switch voltage V_{s2} : 10V/division Switch voltage V_{s4} : 10V/division, 10 μ s/division.

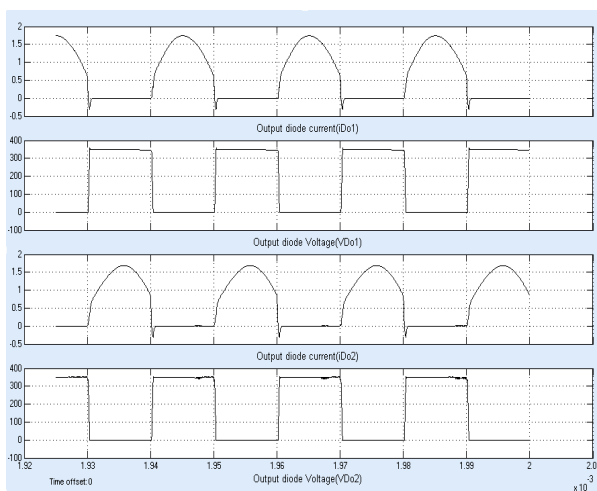


Figure.8

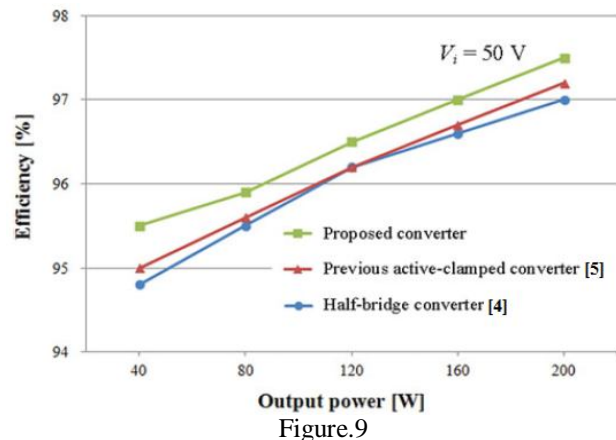


Figure.9

Figure.8. Experimental results: Output diode voltage V_{D01} : 10V/division; Output diode current i_{D01} : 1A/division; Output diode voltage i_{D02} : 1A/division, 10 μ s/division at 50-V input voltage. Figure.9. Experimental results: measured efficiency of the proposed converter compared with the efficiency of the previous converter at 50-V input voltage. Figure.9 shows efficiency comparison at 50-V input voltage.

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The proposed converter achieves the efficiency of 97.5% for 200-W output power. The previous active-clamped converter achieves the efficiency of 97.2% for 200-W output power. The efficiency of 0.3% is improved by proposed converter at 50-V input voltage for 200-W output power. The previous half-bridge converter achieves the efficiency of 97.0% for 200-W output power. Figure.10.shows the output voltage V_o and output load current i_o in case of the conventional and modified PI controller.

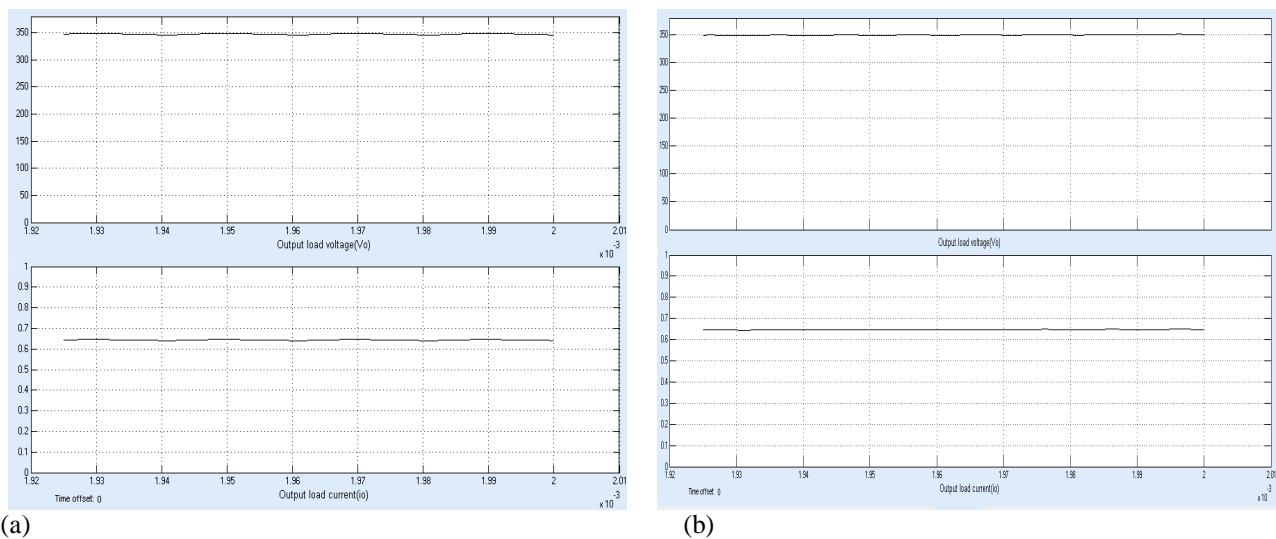


Figure.10.Experimental results (output voltage V_o : 50V/division; output load current i_o : 0.1A/division): (a) in case of conventional PI controller, (b) in case of modified PI controller.

V.CONCLUSION

A dual active-clamping circuit with high efficiency has been proposed. Analysis, design, and simulation and experimental results for the proposed converter have also been presented. This proposed converter combines the dual active-clamping circuit and the resonant voltage doubler rectifier circuit across the power transformer with the topology proposed for soft switching dc-dc converter. The resonant voltage doubler rectifier circuit provides two resonant-current paths formed by the leakage inductance of the power transformer and the resonant capacitor. In addition, the ZCS mechanism of the switches by dual active-clamping and auxiliary switches, they reduce the switching losses and the reverse-recovery losses. The modified PI controller is suggested to reduce the output voltage variation. The proposed converter achieves a high-efficiency of 97.5% at 50-V input voltage for 200-W output power.

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BIOGRAPHY



B.GAMYA received B.Tech degree in Electrical and Electronic Engineering from Jawaharlal Nehru Technological University, Anaparthi, India in 2012. Currently She is pursuing M.Tech, Power Electronics in Sreenivasa Institute of Technology and Management Studies, Chittoor, A.P, India. Her research interests are development in Power Electronics.



RAMESH R.HALAKURKI Currently working as Professor in Department of Electrical and Electronics Engineering, Sreenivasa Institute of Technology and Management Studies, Chittoor, A.P, India. His research interests include Power Electronics and Neural networks. He is a life member of ISTE, Associate Member of IE.